

# BQ25176J : 1セルリチウムイオンおよびLiFePO<sub>4</sub>向け800mA JEITA準拠リニアバッテリチャージャ、VINDPM搭載

## 1 特長

- 最大30Vの入力電圧に対応
- 入力電圧のダイナミック・パワー・マネージメント(VINDPM)
- 自動スリープ・モードによる消費電力の低減
  - バッテリ・リーク電流:350nA
  - 充電ディセーブル時の入力リーク電流 80μA
- 1セルのリチウムイオン、リチウムポリマ、LiFePO<sub>4</sub>をサポート
- 外付け抵抗によりプログラム可能な動作
  - VSETによりバッテリ・レギュレーション電圧を設定:
    - リチウムイオン:4.05V、4.15V、4.2V、4.35V、4.4V
    - LiFePO<sub>4</sub>:3.5V、3.6V、3.7V
  - ISETにより充電電流を10mA～800mAに設定
- 高精度
  - ±0.5%の充電電圧精度
  - ±10%の充電電流精度
- 充電機能
  - プリチャージ電流:ISETの20%
  - 終端電流:ISETの10%
  - NTCサーミスタ入力によるバッテリ温度監視
  - JEITA範囲全体にわたる充電動作をTSピンで制御
  - ステータスおよびフォルト表示用のオープン・ドレン出力
- フォルト保護機能内蔵
  - 26VのIN過電圧保護
  - VSETによるOUT過電圧保護
  - 1000mAの過電流保護機能
  - 125°Cのサーマル・レギュレーション、150°Cのサーマル・シャットダウン保護
  - OUTの短絡保護
  - VSET、ISETピンの短絡/開放保護

## 2 アプリケーション

- 完全ワイヤレスヘッドセット
- ウェアラブル・アクセサリ、スマート・バンド
- 美容および理容
- 電動歯ブラシ
- フリート管理、アセット追跡

## 3 概要

BQ25176Jは、スペースに制約のあるポータブルアプリケーションを対象とした、1セルのリチウムイオン、リチウムポリマ、LiFePO<sub>4</sub>バッテリ用の統合型800mAリニアチャージャです。このデバイスには、バッテリを充電する電源出力が1つあります。平均的なシステム負荷において安全タイマの継続時間内にバッテリがフル充電されるならば、システム負荷をバッテリと並列に配置できます。システム負荷をバッテリと並列に配置した場合、充電電流がシステムとバッテリの間で共有されます。

このデバイスは、リチウムイオン/リチウムポリマバッテリ充電用の次の4つのフェーズを備えています。これらは、バッテリ電圧をV<sub>BAT\_SHORT</sub>まで引き上げるトリクル充電、完全に放電されたバッテリを回復するプリチャージ、大量の電荷を供給する定電流の高速充電、最大容量に達するための電圧レギュレーションです。

すべての充電フェーズで、内部の制御ループがICの接合部温度を監視し、内部温度スレッショルドT<sub>REG</sub>を超えた場合には充電電流を減少させます。

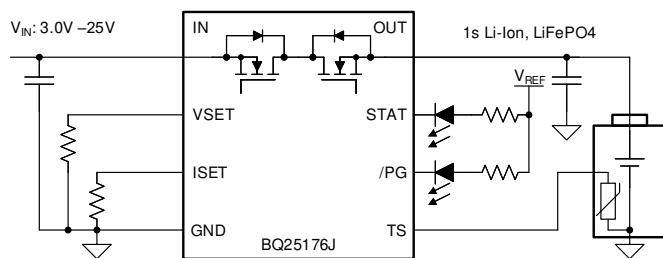
充電器の電力段と充電電流センス機能は完全に統合されています。充電器には、高精度の電流および電圧レギュレーションループ、充電ステータスの表示、および充電の自動終了の機能があります。充電電圧と高速充電電流は、外付け抵抗によりプログラム可能です。プリチャージおよび終端電流スレッショルドは、高速充電電流の設定に応じて設定されます。

### パッケージ情報

部品番号 <sup>(1)</sup>	パッケージ	パッケージ・サイズ <sup>(2)</sup>	本体サイズ(公称)
BQ25176J	DSG (WSON, 8)	2.0mm × 2.0mm	2.0mm × 2.0mm

(1) 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。

(2) パッケージ・サイズ(長さ×幅)は公称値であり、該当する場合はピンも含まれます。



概略回路図

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## 4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

DATE	REVISION	NOTES
October 2023	*	Initial Release

## 5 Pin Configuration and Functions

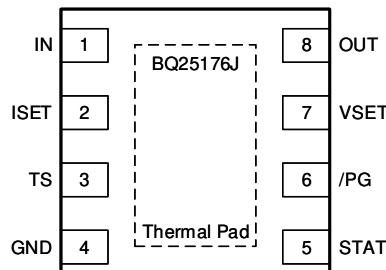


図 5-1. DSG Package 8-Pin WSON Top View

表 5-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	NUMBER		
IN	1	P	Input power, connected to external DC supply. Bypass IN with at least 1- $\mu$ F capacitor to GND, placed close to the IC.
ISET	2	I	Programs the device fast-charge current. External resistor from ISET to GND defines fast charge current value. Expected range is 30 k $\Omega$ (10 mA) to 375 $\Omega$ (800 mA). $ICHG = K_{ISET} / R_{ISET}$ . Precharge current is defined as 20% of ICHG. Termination current is defined as 10% of ICHG.
TS	3	I	Temperature qualification voltage input. Connect a negative temperature coefficient (NTC) thermistor directly from TS to GND (AT103-2 recommended). Charge suspends when the TS pin voltage is out of range. If TS function is not needed, connect an external 10-k $\Omega$ resistor from this pin to GND. Pulling TS < $V_{TS\_ENZ}$ will disable the charger.
GND	4	–	Ground pin
STAT	5	O	Open drain charger status indication output. Connect to pull-up rail via 10-k $\Omega$ resistor. LOW indicates charge in progress. HIGH indicates charge complete or charge disabled. When a fault condition is detected STAT pin blinks at 1 Hz.
$\overline{PG}$	6	O	Open drain charge power good indication output. Connect to pull-up rail via 10-k $\Omega$ resistor. $\overline{PG}$ pulls low when $V_{IN} > V_{IN\_LOWV}$ and $V_{OUT} + V_{SLEEPZ} < V_{IN} < V_{IN\_OV}$ .
VSET	7	I	Programs the regulation voltage for OUT pin with a pull-down resistor. Valid resistor range is 18.2 k $\Omega$ to 100 k $\Omega$ , values outside this range will suspend charge. Refer to セクション 7.3.1.2 for voltage level details. Recommend using $\pm 1\%$ tolerance resistor with <200 ppm/ $^{\circ}$ C temperature coefficient.
OUT	8	P	Battery connection. System Load may be connected in parallel to battery. Bypass OUT with at least 1- $\mu$ F capacitor to GND, placed close to the IC.
Thermal Pad	—	—	Exposed pad beneath the IC for heat dissipation. Solder thermal pad to the board with vias connecting to solid GND plane.

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Voltage	IN	-0.3	30	V
Voltage	OUT	-0.3	13	V
Voltage	ISET, PG, STAT, TS, VSET	-0.3	5.5	V
Output Sink Current	PG, STAT		5	mA
Junction temperature	T <sub>J</sub>	-40	150	°C
Storage temperature	T <sub>stg</sub>	-65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute maximum ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.

### 6.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2500
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup>	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V <sub>IN</sub>	Input voltage		3.0	25	V
V <sub>OUT</sub>	Output voltage			4.4	V
I <sub>OUT</sub>	Output current			0.8	A
T <sub>J</sub>	Junction temperature	-40		125	°C
C <sub>IN</sub>	IN capacitor	1			µF
C <sub>OUT</sub>	OUT capacitor	1			µF
R <sub>VSET</sub>	VSET resistor	18.2		100	kΩ
R <sub>VSET_TOL</sub>	Tolerance for VSET resistor	-1		1	%
R <sub>VSET_TEMPCO</sub>	Temperature coefficient for VSET resistor			200	ppm/°C
R <sub>ISET</sub>	ISET resistor	0.375		30	kΩ
R <sub>TS</sub>	TS thermistor resistor (recommend 103AT-2)		10		kΩ

## 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		BQ25176J	UNIT
		DSG	
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance (JEDEC <sup>(1)</sup> )	75.2	°C/W
$R_{\theta JC(\text{top})}$	Junction-to-case (top) thermal resistance	93.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	41.8	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	3.8	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	41.7	°C/W
$R_{\theta JC(\text{bot})}$	Junction-to-case (bottom) thermal resistance	17.0	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Electrical Characteristics

3.0V <  $V_{IN}$  < 18V and  $V_{IN} > V_{OUT} + V_{SLEEP}$ ,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$ , and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>QUIESCENT CURRENTS</b>					
$I_{Q\_OUT}$	Quiescent output current (OUT)	OUT= 4.2V, IN floating or IN = 0V - 5V, Charge Disabled, $T_J = 25^{\circ}C$	0.35	0.6	$\mu A$
		OUT= 4.2V, IN floating or IN = 0V - 5V, Charge Disabled, $T_J < 105^{\circ}C$	0.35	0.8	$\mu A$
$I_{SD\_IN\_TS}$	Shutdown input current (IN) with charge disabled via TS pin	IN = 5V, Charge Disabled ( $V_{TS} < V_{TS\_ENZ}$ ), no battery	80	110	$\mu A$
$I_{STANDBY\_IN}$	Standby input current (IN) with charge terminated	IN = 5V, Charge Enabled, charge terminated	190		$\mu A$
$I_{Q\_IN}$	Quiescent input current (IN)	IN = 5V, OUT = 3.8V, Charge Enabled, ICHG = 0A	0.45	0.6	mA
<b>INPUT</b>					
$V_{IN\_OP}$	IN operating range		3.0	25	V
$V_{IN\_LOWV}$	IN voltage to start charging	IN rising	3.05	3.09	3.15
$V_{IN\_LOWV}$	IN voltage to stop charging	IN falling	2.80	2.95	3.10
$V_{SLEEPZ}$	Exit SLEEP mode threshold	IN rising, $V_{IN} - V_{OUT}$ , OUT = 4V	30	55	80
$V_{SLEEP}$	Enter SLEEP mode threshold	IN falling, $V_{IN} - V_{OUT}$ , OUT = 4V	5	30	50
$V_{IN\_OV}$	VIN overvoltage rising threshold	IN rising	26.0	26.5	27.0
$V_{IN\_OVZ}$	VIN overvoltage falling threshold	IN falling	25.0	25.5	26.0
$V_{IN\_DPM}$	Input voltage DPM threshold	VOUT = 2.9V, VSET = 4.35V, measured at IN pin	3.15	3.25	3.35
<b>CONFIGURATION PINS SHORT/OPEN PROTECTION</b>					
$R_{ISET\_SHORT}$	Highest resistor value considered short	$R_{ISET}$ below this at startup, charger does not initiate charge, power cycle or TS toggle to reset		350	$\Omega$
$R_{VSET\_SHORT}$	Highest resistor value considered short	$R_{VSET}$ below this at startup, charger does not initiate charge, power cycle or TS toggle to reset		2.8	k $\Omega$
$R_{VSET\_OPEN}$	Lowest resistor value considered open	$R_{VSET}$ below this at startup, charger does not initiate charge, power cycle or TS toggle to reset	200		k $\Omega$
<b>BATTERY CHARGER</b>					
$V_{DO}$	Dropout voltage ( $V_{IN} - V_{OUT}$ )	VIN falling, VOUT = 4.35V, IOUT = 500mA	425		mV
$V_{REG\_ACC}$	OUT charge voltage regulation accuracy	$T_J = 25^{\circ}C$ , all VSET settings	-0.5	0.5	%
		$T_J = -40^{\circ}C$ to $125^{\circ}C$ , all VSET settings	-0.8	0.8	%
$I_{CHG\_RANGE}$	Typical charge current regulation range	$V_{OUT} > V_{BAT\_LOWV}$	10	800	mA
$K_{ISET}$	Charge current setting factor, $I_{CHG} = K_{ISET} / R_{ISET}$	10mA < ICHG < 800mA	270	300	330
$I_{CHG\_ACC}$	Charge current accuracy	$R_{ISET} = 375\Omega$ , OUT = 3.8V	720	800	880
		$R_{ISET} = 600\Omega$ , OUT = 3.8V	450	500	550
		$R_{ISET} = 3.0k\Omega$ , OUT = 3.8V	90	100	110
		$R_{ISET} = 30k\Omega$ , OUT = 3.8V	9	10	11
$I_{PRECHG}$	Typical pre-charge current, as percentage of ICHG	$V_{OUT} < V_{BAT\_LOWV}$		20	%

## 6.5 Electrical Characteristics (続き)

$3.0V < V_{IN} < 18V$  and  $V_{IN} > V_{OUT} + V_{SLEEP}$ ,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$ , and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
$I_{PRECHG\_ACC}$	$R_{ISET} = 375\Omega$ , OUT = 2.5V	144	160	176	mA	
	$R_{ISET} = 600\Omega$ , OUT = 2.5V	85	100	110	mA	
	$R_{ISET} = 3.0k\Omega$ , OUT = 2.5V	18	20	22	mA	
	$R_{ISET} = 30k\Omega$ , OUT = 2.5V	1.4	2	2.6	mA	
$I_{TERM}$	$V_{OUT} = V_{REG}$		10		%	
$I_{TERM\_ACC}$	$R_{ISET} = 600\Omega$ , OUT = VREG = 4.2V	45	50	55	mA	
	$R_{ISET} = 3.0k\Omega$ , OUT = VREG = 4.2V	8.5	10	11.5	mA	
	$R_{ISET} = 30k\Omega$ , OUT = VREG = 4.2V	0.4	1	1.6	mA	
$V_{BAT\_SHORT}$	Output (OUT) short circuit voltage rising threshold for Li-Ion chemistry	OUT rising	2.1	2.2	2.3	V
$V_{BAT\_SHORT}$	Output (OUT) short circuit voltage rising threshold for LiFePO <sub>4</sub> chemistry	OUT rising, VSET configured for LiFePO <sub>4</sub>	1.1	1.2	1.3	V
$V_{BAT\_SHORT\_HYS}$	Output (OUT) short circuit voltage hysteresis	OUT falling		200		mV
$I_{BAT\_SHORT}$	OUT short circuit charging current	$V_{OUT} < V_{BAT\_SHORT}$	12	16	20	mA
$V_{BAT\_LOWV}$	Pre-charge to fast-charge transition threshold for Li-Ion chemistry	OUT rising	2.7	2.8	3.0	V
$V_{BAT\_LOWV}$	Pre-charge to fast-charge transition threshold for Li-FePO <sub>4</sub> chemistry	OUT rising, VSET configured for LiFePO <sub>4</sub>	1.9	2.0	2.1	V
$V_{BAT\_LOWV\_HYS}$	Battery LOWV hysteresis	OUT falling		100		mV
$V_{RECHG}$	Battery recharge threshold for Li-Ion chemistry	OUT falling, $V_{REG\_ACC} - V_{OUT}$	75	100	125	mV
$V_{RECHG}$	Battery recharge threshold for LiFePO <sub>4</sub> chemistry	OUT falling, VSET configured for LiFePO <sub>4</sub> , $V_{REG\_ACC} - V_{OUT}$	175	200	225	mV
$R_{ON}$	Charging path FET on-resistance	$I_{OUT} = 400mA$ , $T_J = 25^{\circ}C$		845	1000	$m\Omega$
		$I_{OUT} = 400mA$ , $T_J = -40 - 125^{\circ}C$		845	1450	$m\Omega$

### BATTERY CHARGER PROTECTION

$V_{OUT\_OVP}$	OUT overvoltage rising threshold	$V_{OUT}$ rising, as percentage of VREG	103	104	105	%
$V_{OUT\_OVP}$	OUT overvoltage falling threshold	$V_{OUT}$ falling, as percentage of VREG	101	102	103	%
$I_{OUT\_OCP}$	Output current limit threshold	$I_{OUT}$ rising	0.9	1	1.1	A

### TEMPERATURE REGULATION AND TEMPERATURE SHUTDOWN

$T_{REG}$	Typical junction temperature regulation		125		$^{\circ}C$
$T_{SHUT}$	Thermal shutdown rising threshold	Temperature increasing	150		$^{\circ}C$
	Thermal shutdown falling threshold	Temperature decreasing	135		$^{\circ}C$

### BATTERY-PACK NTC MONITOR

$I_{TS\_BIAS}$	TS nominal bias current		36.5	38	39.5	$\mu A$
$V_{COLD}$	Cold temperature threshold; Charge disabled	TS pin voltage rising (approx. 0°C)	0.99	1.04	1.09	V
	Cold temperature exit threshold; Charge current target increased to 20% $\times$ ISET	TS pin voltage falling (approx. 4°C)	0.83	0.88	0.93	V
$V_{COOL}$	Normal to low temperature charge; Charge current target reduced to 20% $\times$ ISET	TS pin voltage rising (approx. 10°C)	650	680	710	mV
	Low temperature to normal charge; Charge current target returns to ISET	TS pin voltage falling (approx. 13°C)	580	610	640	mV

## 6.5 Electrical Characteristics (続き)

$3.0V < V_{IN} < 18V$  and  $V_{IN} > V_{OUT} + V_{SLEEP}$ ,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$ , and  $T_J = 25^{\circ}C$  for typical values (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
$V_{WARM}$	Normal to warm temperature threshold; Charge current target reduced to $50\% \times ISET$ ; VREG reduced to 4.1V for VSET = 4.15V, 4.2V, 4.35 V, 4.4 V	TS pin voltage falling (approx. 45°C)	176	188	200	mV
	Warm to normal temperature threshold; Charge current target increased to $ISET$ ; VREG increased to VSET for VSET = 4.15V, 4.2 V, 4.35 V, 4.4 V	TS pin voltage rising (approx. 40°C)	208	220	232	mV
$V_{HOT}$	Warm to hot temperature threshold; charge disabled	TS pin voltage falling (approx. 55°C)	125	135	145	mV
	Hot to warm temperature threshold; Charge current target increased to $50\% \times ISET$ ; VREG set to 4.1V for VSET = 4.15V, 4.2 V, 4.35 V, 4.4 V	TS pin voltage rising (approx. 51°C)	148	158	168	mV
$V_{TS\_ENZ}$	Charge Disable threshold. Crossing this threshold shall shutdown IC	TS pin voltage falling	40	50	60	mV
$V_{TS\_EN}$	Charge Enable threshold. Crossing this threshold shall restart IC operation	TS pin voltage rising	65	75	85	mV
$V_{TS\_CLAMP}$	TS maximum voltage clamp	TS pin open-circuit (float)	2.3	2.6	2.9	V
<b>LOGIC OUTPUT PIN (STAT, PG)</b>						
$V_{OL}$	Output low threshold level	Sink current = 5mA		0.4	V	
$I_{OUT\_BIAS}$	High-level leakage current	Pull up rail 3.3V		1	$\mu$ A	

## 6.6 Timing Requirements

		MIN	NOM	MAX	UNIT
<b>BATTERY CHARGER</b>					
$t_{TS\_DUTY\_OFF}$	TS turn-off time during TS duty cycle mode	2			s
$t_{OUT\_OCP\_DGL}$	Deglitch time for $I_{OUT\_OCP}$ , $I_{OUT}$ rising	100			$\mu$ s
$t_{PRECHG}$	Pre-charge safety timer accuracy	28.5	30	31.5	min
$t_{SAFETY}$	Fast-charge safety timer accuracy	9.5	10	10.5	hr

## 6.7 Typical Characteristics

$C_{IN} = 1 \mu F$ ,  $C_{OUT} = 1 \mu F$ ,  $V_{IN} = 5 V$ ,  $V_{OUT} = 3.8 V$  (unless otherwise specified)

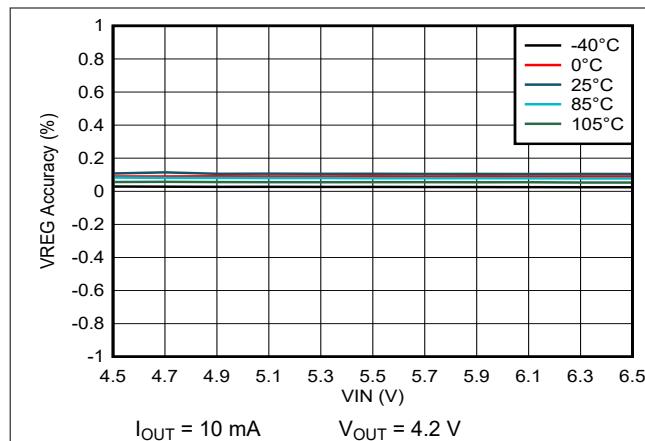


図 6-1. Line Regulation

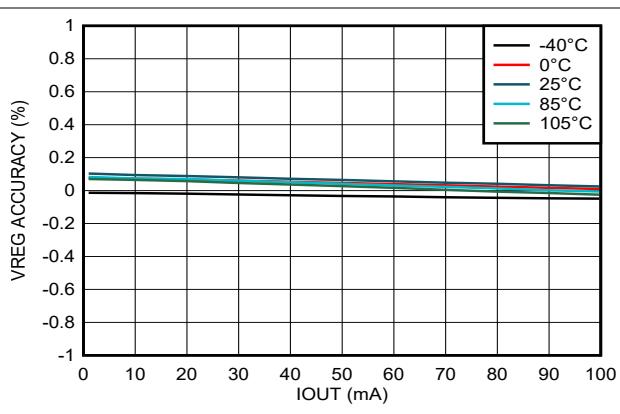


図 6-2. Load Regulation

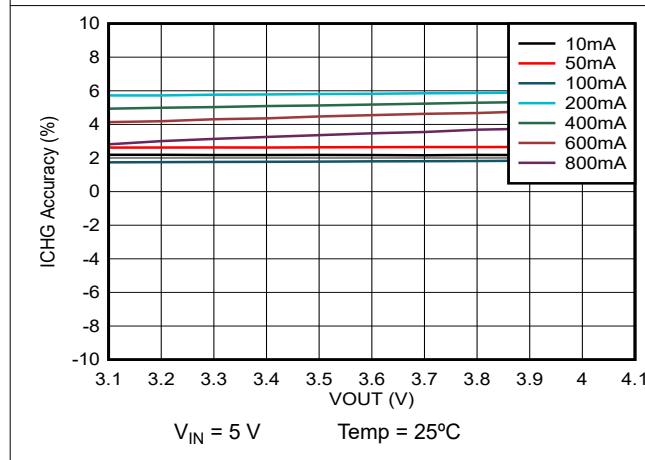


図 6-3. ICHG Accuracy vs V<sub>OUT</sub>

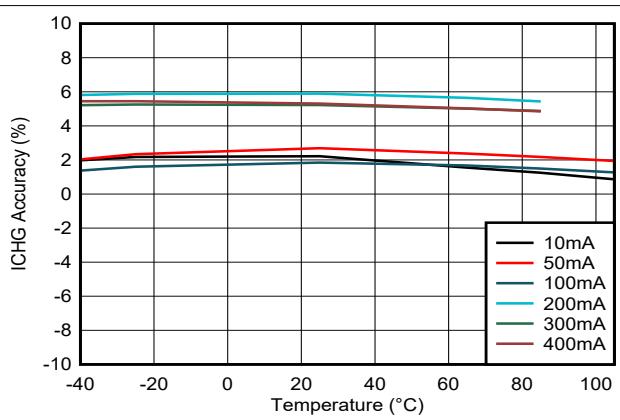
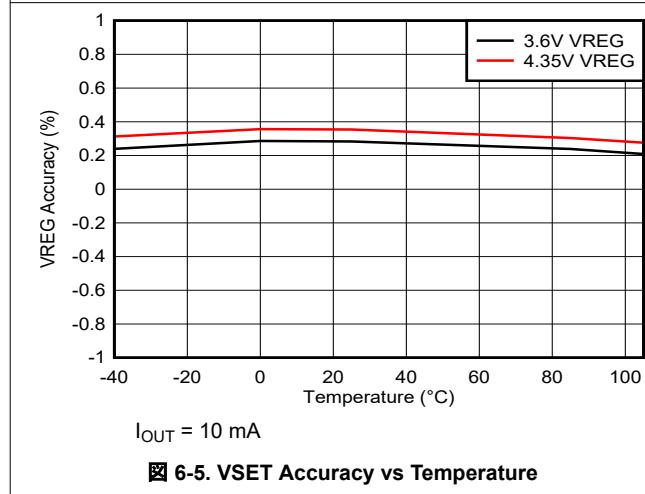


図 6-4. ICHG Accuracy vs Temperature



$I_{OUT} = 10 \text{ mA}$

図 6-5. VSET Accuracy vs Temperature

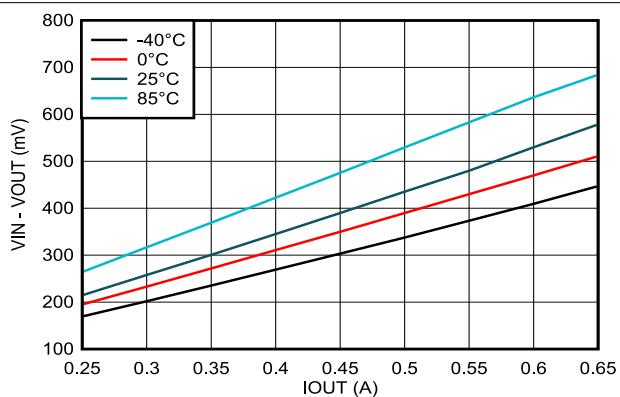


図 6-6. Dropout Voltage vs Output Current

## 6.7 Typical Characteristics (continued)

$C_{IN} = 1 \mu F$ ,  $C_{OUT} = 1 \mu F$ ,  $V_{IN} = 5 V$ ,  $V_{OUT} = 3.8 V$  (unless otherwise specified)

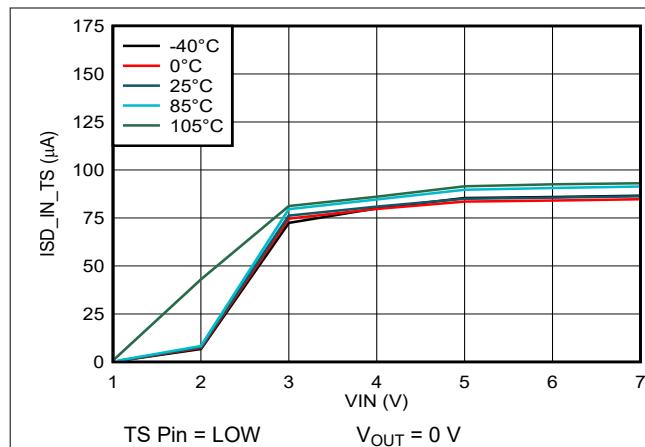


图 6-7. Input Shutdown Current vs Input Voltage

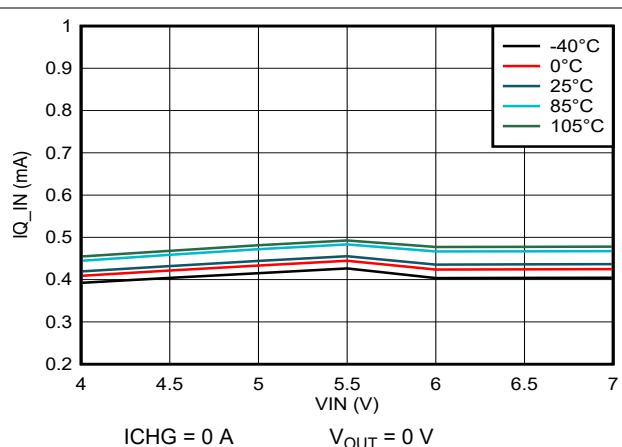


图 6-8. Input Quiescent Current vs Input Voltage

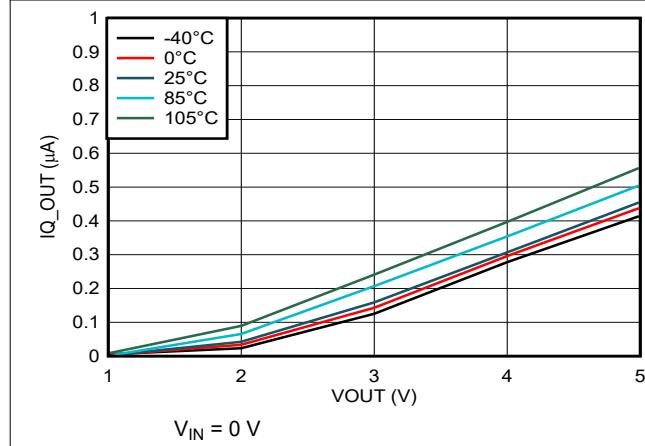


图 6-9. Output Quiescent Current vs Output Voltage

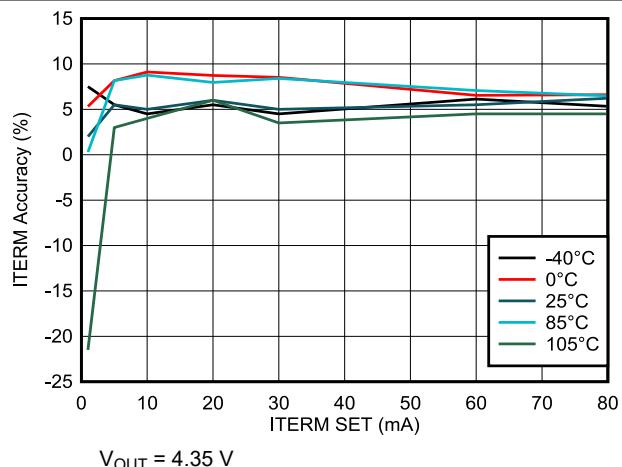


图 6-10. Termination Current Accuracy vs Termination Current Setting

## 7 Detailed Description

### 7.1 Overview

The BQ25176J is an integrated 800-mA linear charger for 1-cell Li-Ion, Li-Polymer, and LiFePO<sub>4</sub> batteries. The device has a single power output that charges the battery. The system load can be placed in parallel with the battery, as long as the average system load does not prevent the battery from charging fully within the safety timer duration. When the system load is placed in parallel with the battery, the output current is shared between the system and the battery.

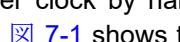
The device has four phases for charging a Li-Ion/Li-Poly battery: trickle charge to bring the battery voltage up to  $V_{BAT\_SHORT}$ , precharge to recover a fully discharged battery, fast-charge constant current to supply the bulk of the charge, and voltage regulation to reach full capacity.

The charger includes flexibility in programming of the fast-charge current and regulation voltage. This charger is designed to work with a standard USB connection or dedicated charging adapter (DC output).

The charger also comes with a full set of safety features: battery temperature monitoring, overvoltage protection, charge safety timers, and configuration pin (VSET, ISET) short and open protection. All of these features and more are described in detail below.

The charger is designed for a single path from the input to the output to charge the battery. Upon application of a valid input power source, the configuration pins are checked for short/open circuit.

If the battery voltage is below the  $V_{BAT\_LOWV}$  threshold, the battery is considered discharged and a preconditioning cycle begins. If the battery voltage is below  $V_{BAT\_SHORT}$ , the charge current is  $I_{BAT\_SHORT}$ . If the battery voltage is higher than  $V_{BAT\_SHORT}$  but lower than  $V_{BAT\_LOWV}$ , the amount of precharge current is 20% of the programmed fast-charge current via the ISET pin. The  $t_{PRECHG}$  safety timer is active, and stops charging after expiration if battery voltage fails to rise above  $V_{BAT\_LOWV}$ .

Once the battery has charged to the  $V_{BAT\_LOWV}$  threshold, Fast Charge Mode is initiated, applying the fast charge current and starting the  $t_{SAFETY}$  timer. The fast charge constant current is programmed using the ISET pin. The constant current phase provides the bulk of the charge. Power dissipation in the IC is greatest in fast charge with a lower battery voltage. If the IC temperature reaches  $T_{REG}$ , the IC enters thermal regulation, slows the timer clock by half, and reduces the charge current as needed to keep the temperature from rising any further.  7-1 shows the typical lithium battery charging profile with thermal regulation. Under normal operating conditions, the IC junction temperature is less than  $T_{REG}$  and thermal regulation is not entered.

Once the battery has charged to the regulation voltage, the voltage loop takes control and holds the battery at the regulation voltage until the current tapers to the termination threshold. The termination threshold is 10% of the programmed fast-charge current.

Further details are described in [セクション 7.3](#).

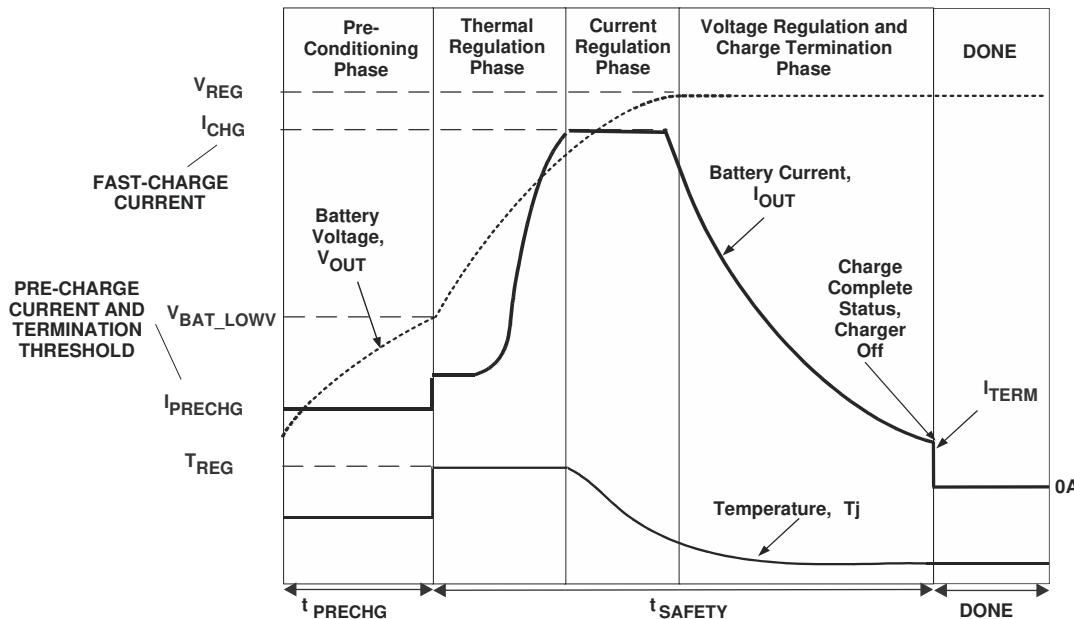
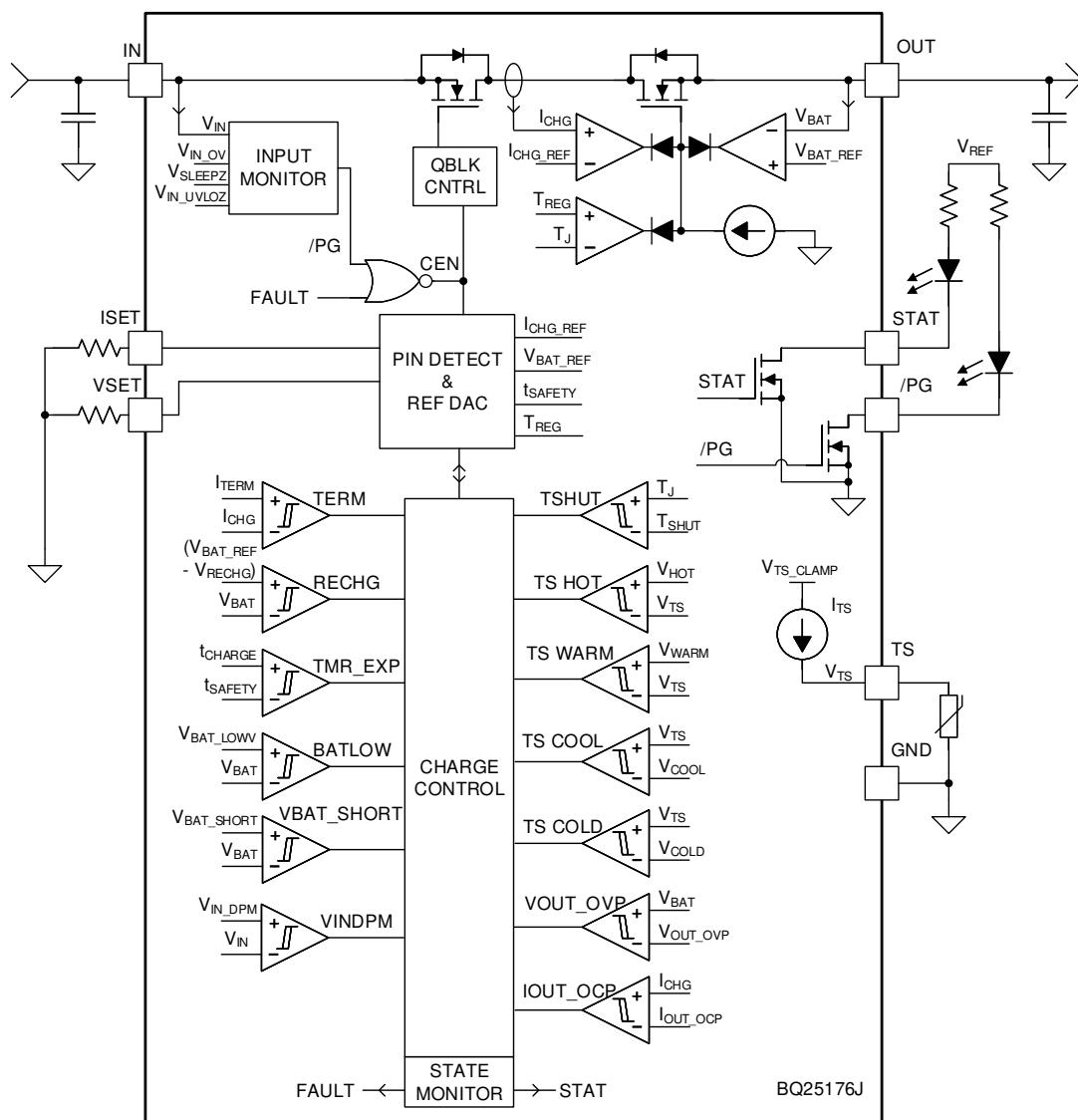


図 7-1. Lithium-Ion Battery Charging Profile with Thermal Regulation

## 7.2 Functional Block Diagram



## 7.3 Feature Description

### 7.3.1 Device Power Up from Input Source

When an input source is plugged in and charge is enabled, the device checks the input source voltage to turn on all the bias circuits. It detects and sets the charge current and charge voltage limits before the linear regulator is started. The power up sequence from input source is as listed:

1. ISET pin detection
2. VSET pin detection to select charge voltage
3. Charger power up

#### 7.3.1.1 ISET Pin Detection

After a valid VIN is plugged in, the device checks the resistor on the ISET pin for a short circuit ( $R_{ISET} < R_{ISET\_SHORT}$ ). If a short condition is detected, the charger remains in the FAULT state until the input or TS pin is toggled. If the ISET pin is open-circuit, the charger proceeds through pin detection and starts the charger with no charge current. This pin is monitored while charging and changes in  $R_{ISET}$  while the charger is operating will immediately translate to changes in charge current.

An external pulldown resistor ( $\pm 1\%$  or better is recommended to minimize charge current error) from the ISET pin to GND sets the charge current as:

$$I_{CHG} = \frac{K_{ISET}}{R_{ISET}} \quad (1)$$

where:

- $I_{CHG}$  is the desired fast-charge current
- $K_{ISET}$  is a gain factor found in the electrical specifications
- $R_{ISET}$  is the pulldown resistor from the ISET pin to GND

For charge currents below 50 mA, an extra RC circuit is recommended on ISET to achieve a more stable current signal. For greater accuracy at lower currents, part of the current-sensing FET is disabled to give better resolution.

#### 7.3.1.2 VSET Pin Detection

VSET pin is used to program the device regulation voltage at end-of-charge using a  $\pm 1\%$  pulldown resistor. The available pulldown resistor and corresponding charging levels are listed in the following table.

表 7-1. VSET Pin Resistor Value Table

RESISTOR	CHARGE VOLTAGE (V)
> 150 kΩ	No charge (open-circuit)
100 kΩ	1-cell LiFePO <sub>4</sub> : 3.50 V
82.5 kΩ	1-cell LiFePO <sub>4</sub> : 3.60 V
61.9 kΩ	1-cell LiFePO <sub>4</sub> : 3.70 V
47.5 kΩ	1-cell Li-Ion: 4.05 V
35.7 kΩ	1-cell Li-Ion: 4.15 V
27.4 kΩ	1-cell Li-Ion: 4.20 V
24.3 kΩ	1-cell Li-Ion: 4.35 V
18.2 kΩ	1-cell Li-Ion: 4.40 V
< 3.0 kΩ	No charge (short-circuit)

If either a short- or open-circuit condition is detected, charger stops operation and remains in the FAULT state until the input or TS pin is toggled.

Once a valid resistor value has been detected, the corresponding charge voltage is latched in and the pin is not continuously monitored during operation. A change in this pin will not be acknowledged by the IC until the input supply or TS pin is toggled.

### 7.3.1.3 Charger Power Up

After VSET, ISET pin resistor values have been validated, the device proceeds to enable the charger. The device automatically begins operation at the correct stage of battery charging depending on the OUT voltage.

### 7.3.2 Battery Charging Features

When charge is enabled, the device automatically completes a charging cycle according to the settings on the VSET, ISET pins without any intervention. The lithium-based charging cycle is automatically terminated when the charging current is below termination threshold, charge voltage is above recharge threshold, and device is not in VINDPM or in thermal regulation (TREG). When a full battery is discharged below the recharge threshold ( $V_{RECHG}$ ), the device automatically starts a new charging cycle. After charge is done, toggling the input supply or the TS pin can initiate a new charging cycle.

#### 7.3.2.1 Lithium-Ion Battery Charging Profile

The device charges a lithium based battery in four phases: trickle charge, precharge, constant current, and constant voltage. At the beginning of a charging cycle, the device checks the battery voltage and regulates current and voltage accordingly.

If the charger is in thermal regulation during charging, the actual charging current is less than the programmed value. In this case, termination is temporarily disabled and the charging safety timer is counted at half the clock rate. For more information, refer to [セクション 7.3.2.4](#).

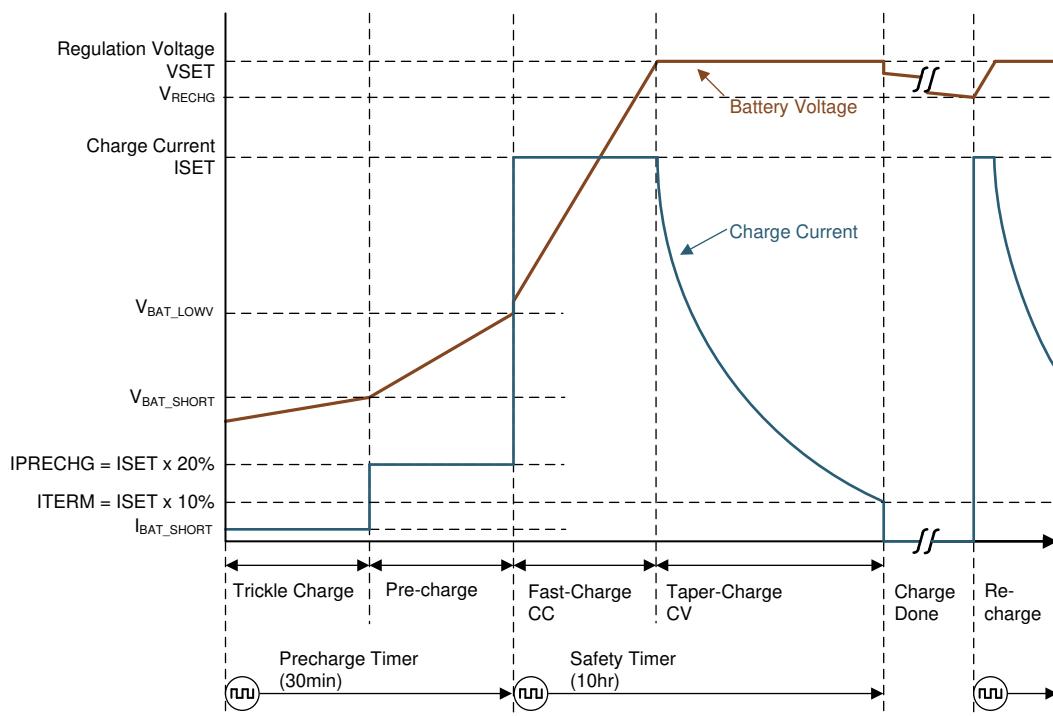


図 7-2. Battery Charging Profile

### 7.3.2.2 Input Voltage Based Dynamic Power Management (VINDPM)

The VINDPM feature is used to detect an input source voltage that is reaching its current limit due to excessive load and causing the voltage to reduce. When the input voltage drops to the VINDPM threshold ( $V_{IN\_DPM}$ ), the internal pass FET reduces the current until there is no further drop in voltage at the input. This prevents a source with voltage less than the  $V_{IN\_DPM}$  to power the OUT pin. This unique feature makes the IC work well with current limited (for example, high impedance) power sources, such as solar panels or inductive charging pads. This is also an added safety feature that helps protect the source from excessive loads.

### 7.3.2.3 Charge Termination and Battery Recharge

The device terminates a charge cycle when the OUT pin voltage is above the recharge threshold ( $V_{RECHG}$ ) and the current is below the termination threshold ( $I_{TERM}$ ). Termination is temporarily disabled when the charger device is in thermal regulation or VINDPM. After charge termination is detected, the linear regulator turns off and the device enters the Standby state. Once the OUT pin drops below the  $V_{RECHG}$  threshold, a new charge cycle is automatically initiated.

### 7.3.2.4 Charging Safety Timers

The device has built-in safety timers to prevent an extended charging cycle due to abnormal battery conditions. The precharge timer is fixed at 30 minutes. The fast-charge safety timer is fixed at 10 hours. When the safety timer expires, the charge cycle ends. A toggle on the input supply or TS pin is required to restart a charge cycle after the safety timer has expired.

During thermal regulation or VINDPM, the safety timer counts at half the clock rate as the actual charge current is likely to be below the ISET setting. For example, if the charger is in thermal regulation throughout the whole charging cycle and the safety timer is 10 hours, then the timer will expire in 20 hours.

During faults which disable charging, such as VIN\_OV, VOUT\_OVP, TSHUT, or TS faults, the timer is suspended. Once the fault goes away, charging and the safety timer resume. If the charging cycle is stopped and started again, the timer gets reset (toggle of the TS pin restarts the timer).

The safety timer restarts counting for the following events:

1. Charging cycle stop and restart (toggle TS pin, charged battery falls below recharge threshold, or toggle input supply)
2. OUT pin voltage crosses the  $V_{BAT\_LOWV}$  threshold in either direction

The precharge safety timer (fixed counter that runs when  $V_{OUT} < V_{BAT\_LOWV}$ ), follows the same rules as the fast-charge safety timer in terms of getting suspended, reset, and counting at half-rate.

### 7.3.2.5 Battery Temperature Qualification (TS Pin)

While charging, the device continuously monitors battery temperature by sensing the voltage at the TS pin. A negative temperature coefficient (NTC) thermistor should be connected between the TS and GND pins (recommend: 103AT-2). If temperature sensing is not required in the application, connect a fixed 10-k $\Omega$  resistor from TS to GND to allow normal operation.

The TS function for BQ25176J is designed to follow the JEITA temperature standard for Li-Ion and Li-Poly batteries; charge current (ISET) and regulation voltage ( $V_{REG}$ ) are reduced based on battery temp (TS). There are four thresholds, Hot-55C, Warm-45C, Cool-10C and Cold-0C.

Normal operation occurs between 10C and 45C, charge current and voltage will be the normal values. When battery is in the Cool temperature range, between 0C and 10C, the charger current level is 20% of ISET value and regulation voltage is not changed. When the battery is in the Warm temperature range, between 45C and 55C, ISET is reduced by 50% and regulation voltage is reduced to 4.1V for VSET settings greater than 4.1V. Regulation voltage is not reduced during the Warm region for VSET settings less than 4.1V. Charge is suspended below Cold temp of 0C and above Hot temp of 55C. When charge is suspended device enters the STANDBY state, and blinks the STAT pin. Once battery temperature returns to normal conditions, charging resumes automatically. See [図 7-3](#).

When charge current is reduced during Cool or Warm temp the safety timer runs at half the clock rate.

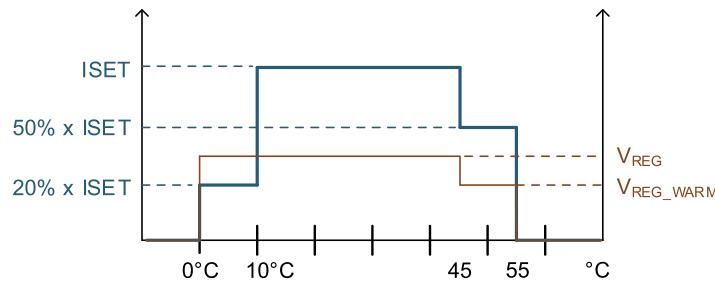


図 7-3. Standard JEITA Profile figure

In addition to battery temperature sensing, the TS pin can be used to disable the charger at any time by pulling TS voltage below  $V_{TS\_ENZ}$ . The device disables the charger and consumes  $I_{SD\_IN\_TS}$  from the input supply. After the TS pin pull-down is released, the device may take up to  $t_{TS\_DUTY\_OFF}$  to turn the  $I_{TS\_BIAS}$  back on. After the source is turned on, the TS pin voltage will go above  $V_{TS\_EN}$ , and re-enable the charger operation. The device treats this TS pin toggle as an input supply toggle, triggering Device Power Up From Input Source (セクション 7.3.1).

### 7.3.3 Status Outputs (PG, STAT)

#### 7.3.3.1 Power Good Indicator (PG Pin)

This open-drain pin pulls LOW to indicate a good input source when:

1. VIN above  $V_{IN\_LOWV}$
2. VIN above  $V_{OUT} + V_{SLEEPZ}$  (not in SLEEP)
3. VIN below  $V_{IN\_OV}$

#### 7.3.3.2 Charging Status Indicator (STAT)

The device indicates the charging state on the open-drain STAT pin. This pin can drive an LED.

表 7-2. STAT Pin State

CHARGING STATE	STAT PIN STATE
Charge completed, charger in Sleep mode or charge disabled ( $V_{TS} < V_{TS\_ENZ}$ )	HIGH
Charge in progress (including automatic recharge)	LOW
Fault ( $V_{IN\_OV}$ , $V_{OUT\_OVP}$ , $I_{OUT\_OCP}$ , TS HOT, TS COLD, TSHUT, TMR_EXP, VSET pin short/open, or ISET pin short)	BLINK at 1Hz

### 7.3.4 Protection Features

The device closely monitors input and output voltages, as well as internal FET current and temperature for safe linear regulator operation.

#### 7.3.4.1 Input Overvoltage Protection (VIN\_OV)

If the voltage at the IN pin exceeds  $V_{IN\_OV}$ , the device turns off after a deglitch,  $t_{VIN\_OV\_DGL}$ . The safety timer suspends counting and the device enters Standby mode. Once the IN voltage recovers to a normal level, the charge cycle and the safety timer automatically resume operation.

#### 7.3.4.2 Output Overvoltage Protection (VOUT\_OVP)

If the voltage at the OUT pin exceeds  $V_{OUT\_OVP}$ , the device immediately stops charging. The safety timer suspends counting and the device enters Standby mode. Once the OUT voltage recovers to a normal level, the charge cycle and the safety timer automatically resume operation.

### 7.3.4.3 Output Overcurrent Protection (I<sub>OUT\_OCP</sub>)

During normal operation, the OUT current should be regulated to the ISET programmed value. However, if a short circuit occurs on the ISET pin, the OUT current may rise to an unintended level. If the current at the OUT pin exceeds I<sub>OUT\_OCP</sub>, the device turns off after a deglitch, t<sub>OUT\_OCP\_DGL</sub>. The safety timer resets the count, and the device remains latched off. An input supply or TS pin toggle is required to restart operation.

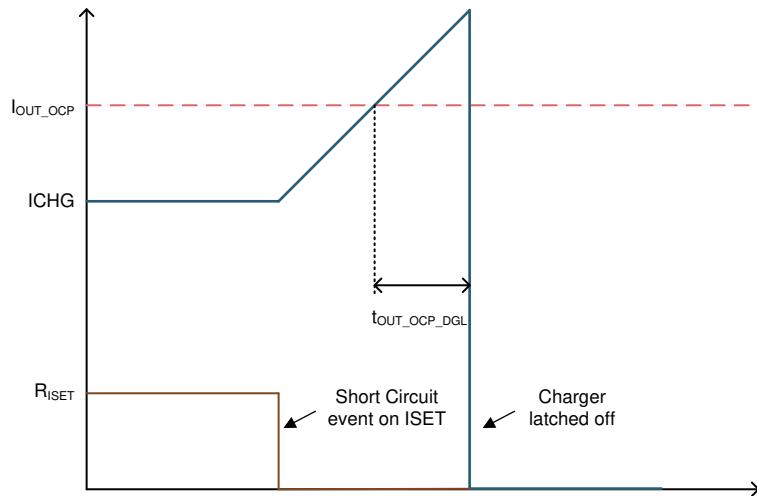


图 7-4. Overcurrent Protection

### 7.3.4.4 Thermal Regulation and Thermal Shutdown (TREG and TSHUT)

The device monitors its internal junction temperature (T<sub>J</sub>) to avoid overheating and to limit the IC surface temperature. When the internal junction temperature exceeds the thermal regulation limit, the device automatically reduces the charge current to maintain the junction temperature at the thermal regulation limit (TREG). During thermal regulation, the actual charging current is usually below the programmed value on the ISET pin. Therefore, the termination comparator for the Lithium-Ion battery is disabled, and the safety timer runs at half the clock rate.

Additionally, the device has thermal shutdown to turn off the linear regulator when the IC junction temperature exceeds the TSHUT threshold. The charger resumes operation when the IC die temperature decreases below the TSHUT falling threshold.

## 7.4 Device Functional Modes

### 7.4.1 Shutdown or Undervoltage Lockout (UVLO)

The device is in the shutdown state if the IN pin voltage is less than V<sub>IN\_LOWV</sub> or the TS pin is below V<sub>TS\_ENZ</sub>. The internal circuitry is powered down, all the pins are high impedance, and the device draws I<sub>SD\_IN\_TS</sub> from the input supply. Once the IN voltage rises above the V<sub>IN\_LOW</sub> threshold and the TS pin is above V<sub>TS\_EN</sub>, the IC enters Sleep mode or Active mode depending on the OUT pin voltage.

### 7.4.2 Sleep Mode

The device is in Sleep mode when V<sub>IN\_LOWV</sub> < V<sub>IN</sub> < V<sub>OUT</sub> + V<sub>SLEEPZ</sub>. The device waits for the input voltage to rise above V<sub>OUT</sub> + V<sub>SLEEPZ</sub> to start operation.

### 7.4.3 Active Mode

The device is powered up and charges the battery when the TS pin is above  $V_{TS\_ENZ}$  and the IN voltage ramps above both  $V_{IN\_LOWV}$  and  $V_{OUT} + V_{SLEEPZ}$ . The device draws  $I_{Q\_IN}$  from the supply to bias the internal circuitry. For details on the device power-up sequence, refer to [セクション 7.3.1](#).

#### 7.4.3.1 Standby Mode

The device is in Standby mode if a valid input supply is present and charge is terminated or if a recoverable fault is detected. The internal circuitry is partially biased, and the device continues to monitor for either  $V_{OUT}$  to drop below  $V_{RECHG}$  or the recoverable fault to be removed.

### 7.4.4 Fault Mode

The fault conditions are categorized into recoverable and nonrecoverable as follows:

- Recoverable, from which the device should automatically recover once the fault condition is removed:
  - $V_{IN\_OV}$
  - $V_{OUT\_OVP}$
  - TS HOT
  - TS COLD
  - TSHUT
- Nonrecoverable, requiring TS pin or input supply toggle to resume operation:
  - $I_{OUT\_OCP}$
  - ISET pin short detected
  - VSET pin short/open detected

## 8 Application and Implementation

### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

A typical application consists of the device configured as a standalone battery charger for single-cell Lithium-Ion, Li-Polymer, or LiFePO<sub>4</sub> chemistries. The charge voltage and number of cells is configured using a pull-down resistor on the VSET pin. The charge current is configured using a pull-down resistor on the ISET pin. A battery thermistor may be connected to the TS pin to allow the device to monitor battery temperature and control charging. Pulling the TS pin below V<sub>TS\_ENZ</sub> disables the charging function. The charger and input supply status is reported via the STAT and PG pins.

### 8.2 Typical Applications

#### 8.2.1 Li-Ion Charger Design Example

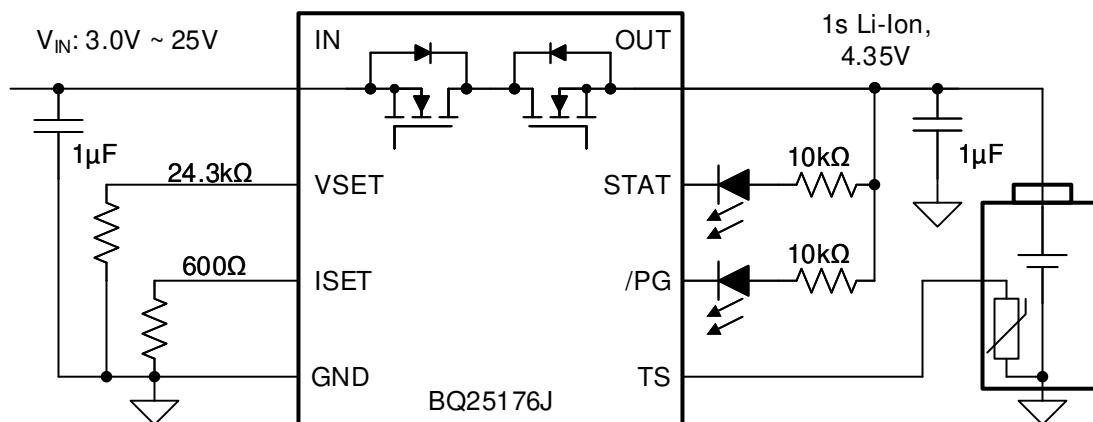


図 8-1. BQ25176J Typical Application for Li-Ion Charging at 500 mA

##### 8.2.1.1 Design Requirements

- Supply voltage = 5 V
- Battery is single-cell Li-Ion
- Fast charge current: I<sub>CHG</sub> = 500 mA
- Charge voltage: V<sub>REG</sub> = 4.35 V
- Termination current: I<sub>TERM</sub> = 10% of I<sub>CHG</sub> or 50 mA
- Precharge current: I<sub>PRECHG</sub> = 20% of I<sub>CHG</sub> or 100 mA
- TS – Battery Temperature Sense = 10-kΩ NTC (103AT)
- TS pin can be pulled down to disable charging

##### 8.2.1.2 Detailed Design Procedure

The regulation voltage is set via the VSET pin to 4.35 V, the input voltage is 5 V and the charge current is programmed via the ISET pin to 500 mA.

$$R_{ISET} = [K_{ISET} / I_{CHG}]$$

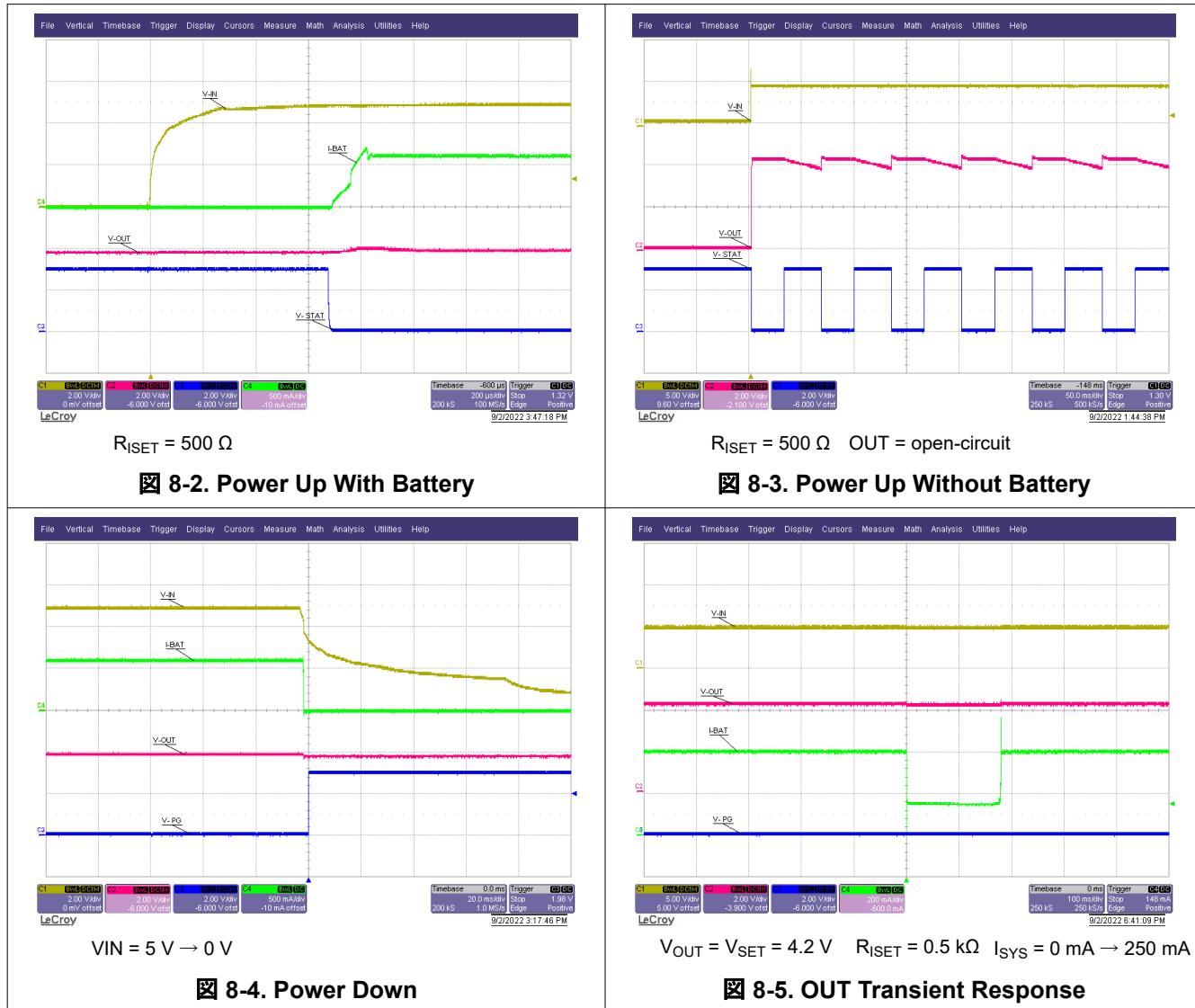
from electrical characteristics table. . . K<sub>ISET</sub> = 300 AΩ

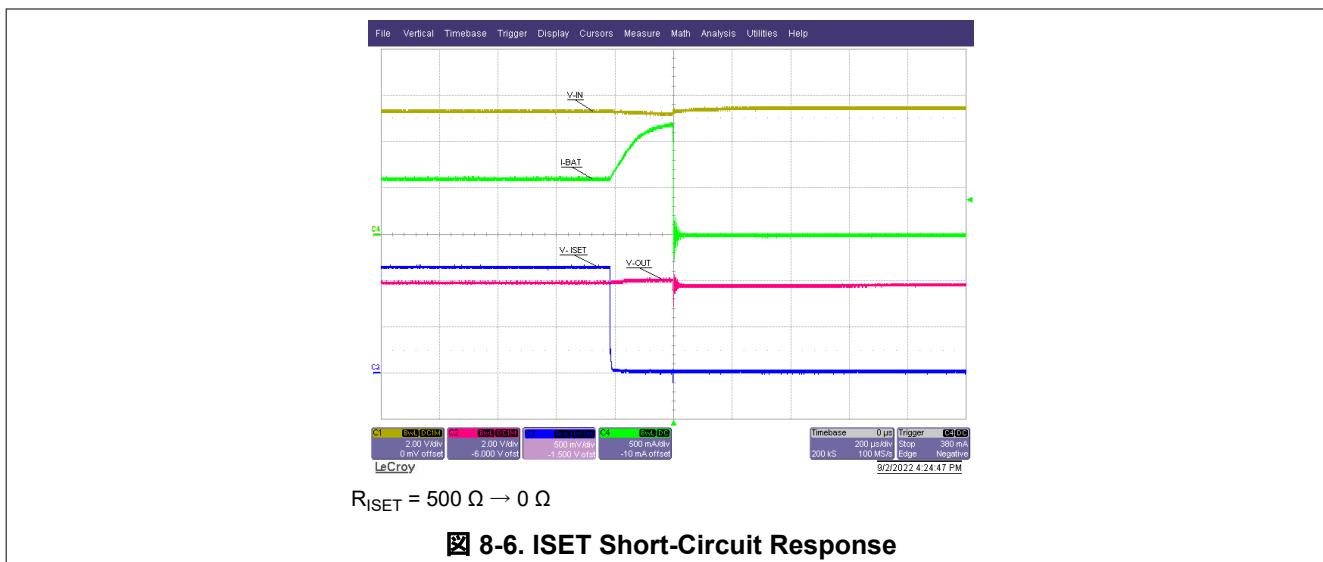
$$R_{ISET} = [300 \text{ A}\Omega / 0.5 \text{ A}] = 600 \Omega$$

Selecting the closest 1% resistor standard value, use a  $604\text{-}\Omega$  resistor between ISET and GND, for an expected  $I_{CHG}$  497 mA.

### 8.2.1.3 Application Curves

$C_{IN} = 1 \mu F$ ,  $C_{OUT} = 1 \mu F$ ,  $V_{IN} = 5 V$ ,  $V_{OUT} = 3.8 V$ ,  $I_{CHG} = 600 \text{ mA}$  (unless otherwise specified)





## 9 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 3.0 V and 25 V (up to 30 V tolerant) and current capability of at least the maximum designed charge current. If located more than a few inches from the IN and GND pins, a larger capacitor is recommended.

## 10 Layout

### 10.1 Layout Guidelines

To obtain optimal performance, the decoupling capacitor from the IN pin to the GND pin and the output filter capacitor from the OUT pin to the GND pin should be placed as close as possible to the device, with short trace runs to both IN, OUT, and GND.

- All low-current GND connections should be kept separate from the high-current charge or discharge paths from the battery. Use a single-point ground technique incorporating both the small signal ground path and the power ground path.
- The high current charge paths into the IN pin and from the OUT pin must be sized appropriately for the maximum charge current in order to avoid voltage drops in these traces.

To achieve correct pin detection, the ISET pin and VSET pin resistors should be placed as close as possible to the device, with short trace runs to both ISET, VSET, and GND.

### 10.2 Layout Example

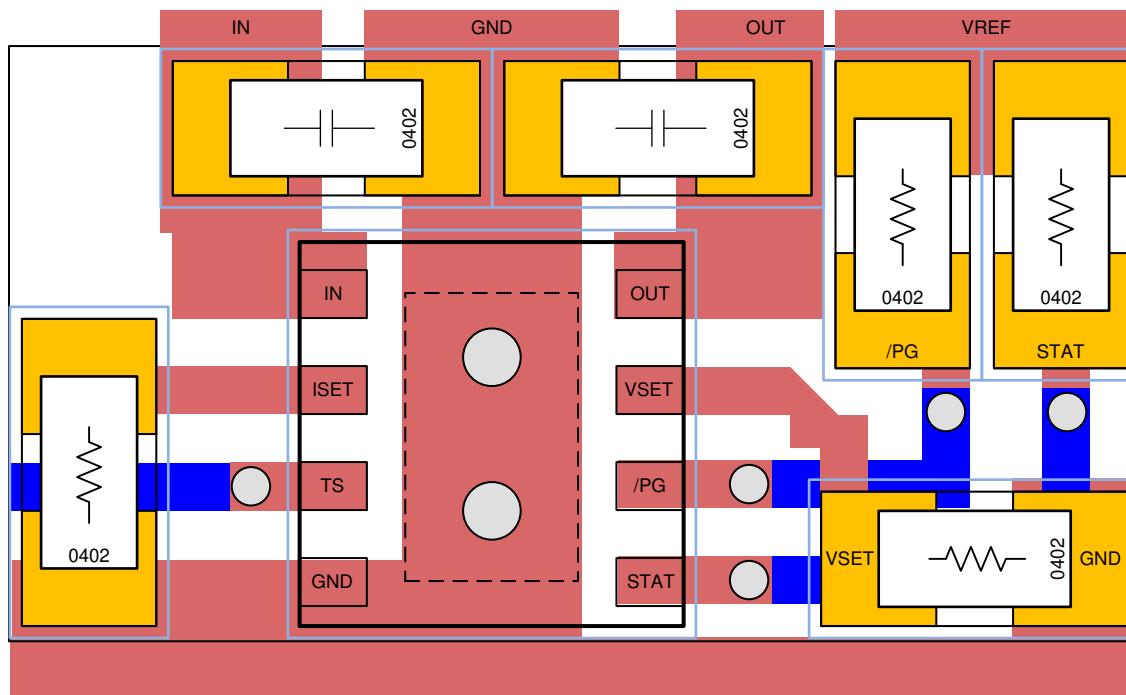


図 10-1. Board Layout Example

## 11 Device and Documentation Support

### 11.1 Device Support

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ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

#### 11.6 用語集

##### テキサス・インスツルメンツ用語集

この用語集には、用語や略語の一覧および定義が記載されています。

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
BQ25176JDSGR	Active	Production	WSON (DSG)   8	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	176J
BQ25176JDSGR.A	Active	Production	WSON (DSG)   8	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	176J

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# GENERIC PACKAGE VIEW

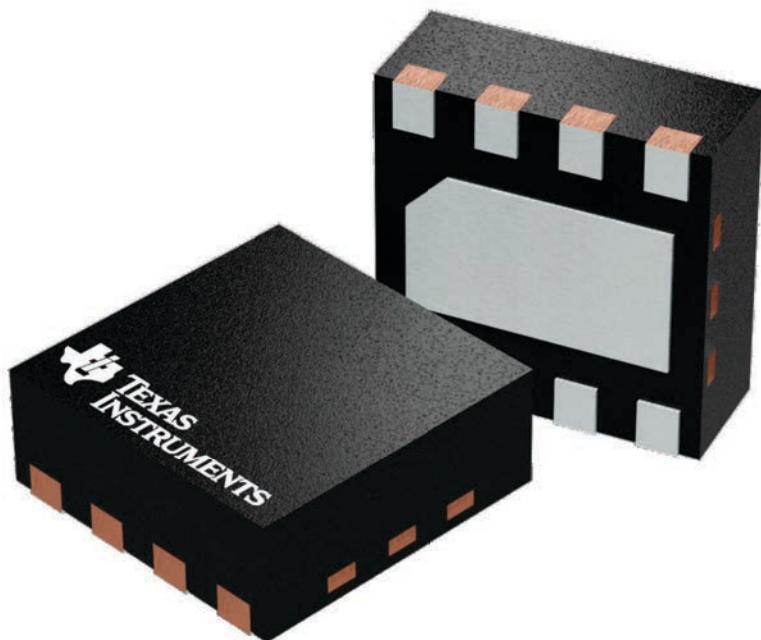
## DSG 8

## WSON - 0.8 mm max height

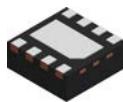
2 x 2, 0.5 mm pitch

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4224783/A

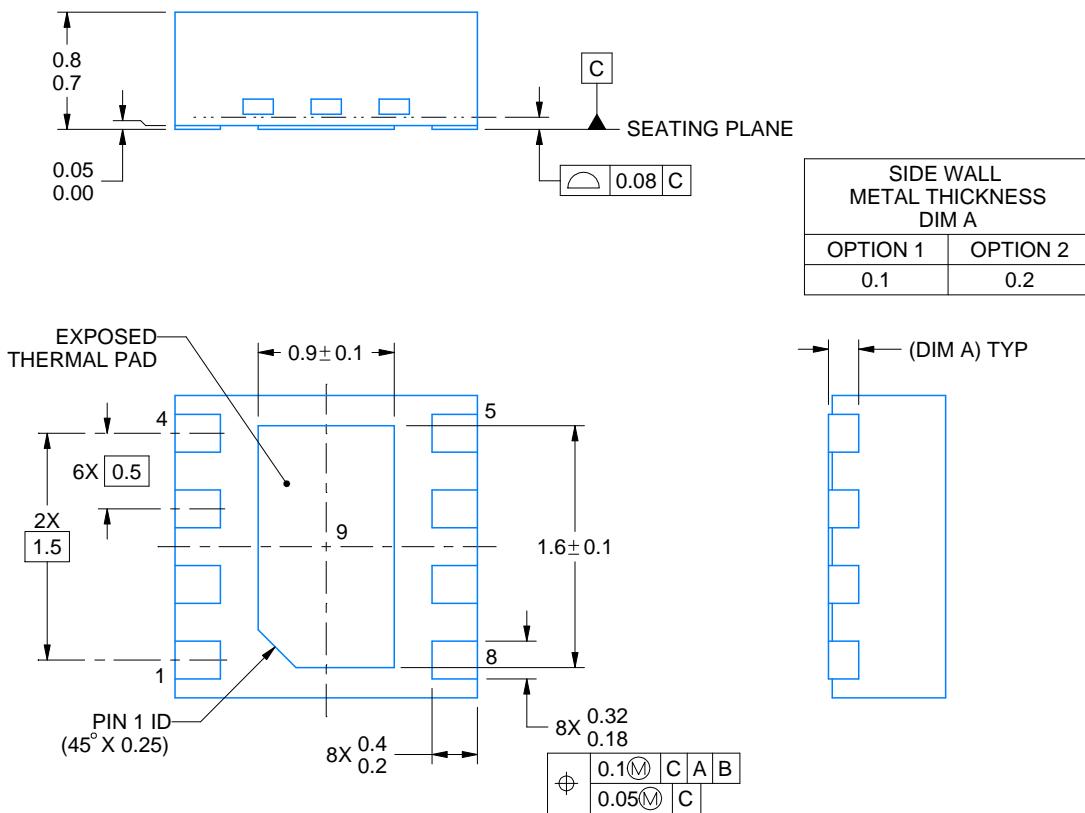
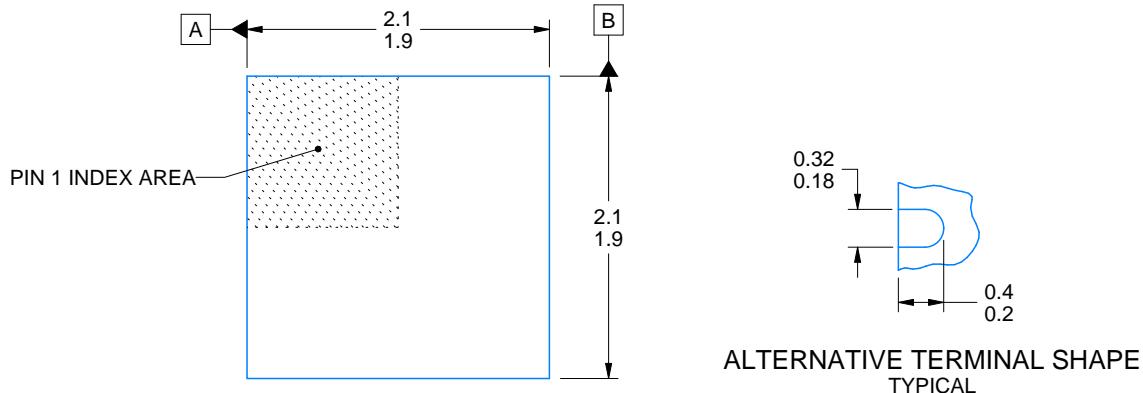


# PACKAGE OUTLINE

DSG0008A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



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## NOTES:

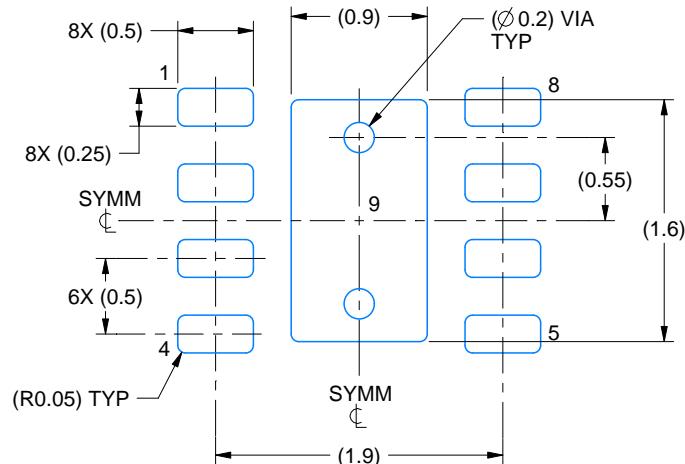
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

## EXAMPLE BOARD LAYOUT

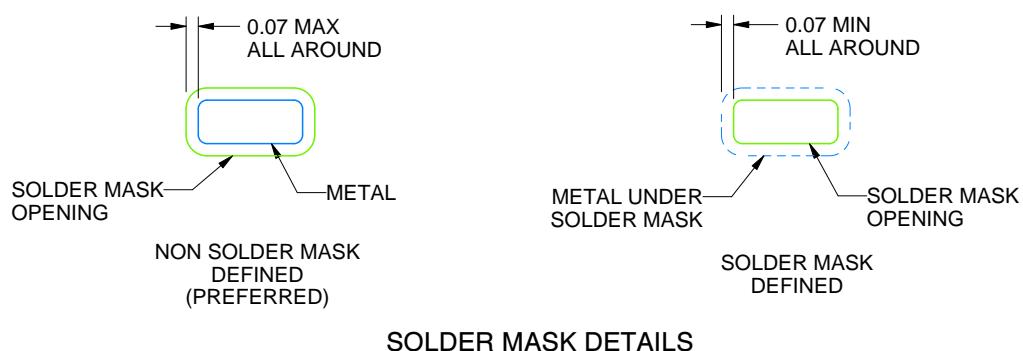
**DSG0008A**

## WSON - 0.8 mm max height

## PLASTIC SMALL OUTLINE - NO LEAD



## LAND PATTERN EXAMPLE



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#### NOTES: (continued)

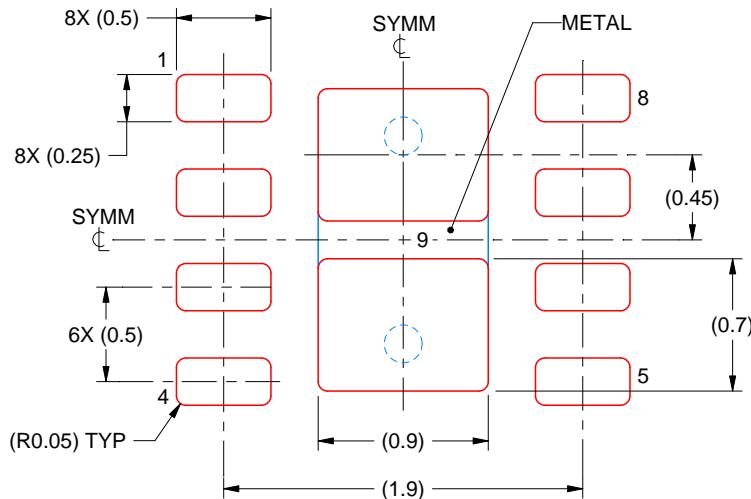
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

# EXAMPLE STENCIL DESIGN

DSG0008A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 9:  
87% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:25X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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